A High–Order Spectral Algorithm for the Numerical Simulation of Layered Media with Uniaxial Hyperbolic Materials

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Abstract
Electromagnetic metamaterials are artificial media assembled from components which have dimensions much smaller than the wavelength of the illuminating radiation. It has been demonstrated that these media can have properties beyond those found in conventional materials with important applications to many areas of science and engineering. Among the collection of such materials currently garnering significant attention are the Hyperbolic Metamaterials. These are highly anisotropic structures which have a hyperbolic dispersion relation due to the fact that one principal component of the relative permittivity or permeability tensor has the opposite sign of the other two. For such materials scattered wave information at all scales is transmitted far away which suggests a number of important applications, the most immediate of which is imaging objects below the diffraction limit (superlensing). Clearly it is of great current interest to have numerical simulation capabilities for these fascinating materials. As the hyperbolic response is quite strong and its nature is very sensitive, numerical simulations of these configurations should be robust and highly accurate. For this reason we focus on High–Order Spectral algorithms which efficiently produce high fidelity solutions. More specifically, we describe a High–Order Perturbation of Surfaces approach which enjoys the greatly reduced operation counts and memory savings of interfacial methods while avoiding the complexities and indefinite linear systems faced by Integral Equation algorithms. We give a full discussion of our formulation in terms of Impedance–Impedance Operators

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(which avoids spurious singularities of other formulations) and implementation details, followed by numerical validation and simulation of results which appear in the engineering literature.

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**MSC Codes:** 65N35; 65N12; 78A45; 78M22; 35Q60; 35J05.

1. Introduction

Electromagnetic metamaterials are artificial media assembled from components which have dimensions much smaller than the wavelength of the illuminating radiation. It has been demonstrated that these media can have properties beyond those found in conventional materials with important applications to many areas of science and engineering [1, 2, 3, 4, 5, 6, 7]. The recent wave of interest in metamaterials was ushered in by the realization of negative index materials (first envisioned by Veselago [8] in 1968) that have permittivity, $\epsilon$, and permeability, $\mu$, simultaneously negative. These have been demonstrated experimentally [9] and allow one to ponder the possibility of perfect cloaks, sub–wavelength imaging, and superlensing to name just a few novel applications [2]. We refer the interested reader to the following survey articles for more examples and details of how such materials are constructed [4, 5, 6, 7].

Among the collection of metamaterials currently garnering significant attention are the so–called Hyperbolic Metamaterials (HMMs). These HMMs are highly anisotropic structures which have a hyperbolic dispersion relation due to the fact that one principal component of the relative permittivity or permeability tensor has the opposite sign of the other two. (From here we focus on non–magnetic materials where the permeability tensor is the identity.) More specifically, if the permittivity tensor is

$$\epsilon = \begin{pmatrix} \epsilon_x & 0 & 0 \\ 0 & \epsilon_y & 0 \\ 0 & 0 & \epsilon_z \end{pmatrix},$$

it is not difficult to construct uniaxial HMMs ($\epsilon_x = \epsilon_y$) where $\text{Re}\{\epsilon_x\} \text{Re}\{\epsilon_z\} < 0$ [3]. In particular, these authors consider thin alternating layers of metal
and dielectric which feature effective permittivities

\[ \epsilon_x = \frac{\epsilon_m + \eta \epsilon_d}{1 + \eta}, \quad \frac{1}{\epsilon_z} = \frac{1}{\epsilon_m + \eta} \left( \frac{1}{\epsilon_m + \eta \epsilon_d} \right). \]

Here \( \epsilon_m \) and \( \epsilon_d \) are the permittivities of the metal and dielectric, respectively, and \( \eta = d_d/d_m \) is the ratio of the layer thicknesses. With \( \epsilon_d > 0 \) and \( \text{Re} \{\epsilon_m\} < 0 \) it is easy to see how an HMM could be built.

To explain the possibilities of these HMMs we recall that, in a homogeneous material layer, a plane–wave solution, \( \exp(i\alpha x + i\gamma z) \), of the time–harmonic Maxwell equations in Transverse Magnetic (TM) polarization will satisfy the dispersion relation

\[ \frac{\alpha^2}{\epsilon_z} + \frac{\gamma^2}{\epsilon_x} = k_0^2, \]

where \( k_0 = \omega/c_0 \), \( \omega \) is the frequency of the radiation, and \( c_0 \) is the speed of light in the vacuum. In a natural dielectric \( \epsilon_x, \epsilon_z > 0 \) and the wavevectors \( (\alpha, \gamma) \) form an ellipse. Of fundamental importance, if \( \alpha \) is small then \( \gamma \) is real and the solution is propagating, while if \( \alpha \) is large then \( \gamma \) is complex with \( \text{Im} \{\gamma\} \geq 0 \). Such solutions decay exponentially and are termed evanescent. Only long wavelengths propagate information away from the material and information at short wavelengths is lost exponentially quickly. This is the diffraction limit.

By contrast, if one can arrange \( \epsilon_x \epsilon_z < 0 \) then the dispersion relation delivers a hyperbola and for all choices of \( \alpha \) we have \( \gamma \) real so that all wavelengths are propagating. Information at all scales is, in theory, transmitted far away from an HMM. This property suggests a number of important applications for these hyperbolic materials, the most immediate of these is the possibility of imaging objects below this diffraction limit [3]. We direct the interested reader to the surveys [4, 5, 6] which describe devices which have been built that can achieve this superlensing, despite the inevitable losses due to absorption.

Interestingly, natural Hyperbolic Materials (HMs) have been identified which display the strong anisotropy of the HMMs discussed above, most notably hexagonal Boron Nitride (hBN) [10, 11]. Though our developments do not depend upon this choice, we will focus on hBN in this contribution as it seems a most promising candidate for subwavelength imaging and other applications. Of particular relevance are its low losses, nanoscale unit cells,
and capability of demonstrating both Type I ($\epsilon_x > 0$ and $\epsilon_z < 0$) and Type II ($\epsilon_x < 0$ and $\epsilon_z > 0$) hyperbolicity \[10\]. (In most publications \[4, 6, 11\] one uses the notation $\epsilon_z = \epsilon_{||}$ for the component parallel to the anisotropy axis and $\epsilon_x = \epsilon_{\perp}$ for the component perpendicular, though this is not universal \[5\].)

Unsurprisingly, it is of great current interest to have numerical simulation capabilities for these fascinating materials. As the hyperbolic response of hBN is quite strong (the reflectivity can be enhanced by several orders of magnitude) and its nature is very sensitive (it is only seen on the range of tens of nanometers) \[10\], numerical simulations of these configurations should be robust and highly accurate. For this reason we focus on High–Order Spectral (HOS) algorithms \[12, 13, 14\] which efficiently produce high fidelity solutions.

All of the classical numerical algorithms are available for the simulation of this problem (e.g., Finite Difference Methods \[15\], Finite Element Methods (FEMs) \[16\], Discontinuous Galerkin Methods \[17\], Spectral Element Methods \[13\], and Spectral Methods \[12, 14\]). Of particular interest to engineers and scientists are black–box FEM solvers, most notably COMSOL Multiphysics \[18\], see e.g. \[19, 20\]. However, these volumetric approaches are greatly disadvantaged with an unnecessarily large number of unknowns for the piecewise homogeneous problems we consider here.

Surface methods are orders of magnitude faster by comparison due to the greatly reduced number of unknowns required to resolve a computation. In addition, these methods enforce far–field boundary conditions exactly, e.g., through their use of the Green function \[21, 22\]. As a result, these approaches are an important alternative which are becoming more widely used by engineers. Among these interfacial methods, the most important are those based upon Integral Equations (IEs) \[21, 23\], but these face difficulties. Most have been addressed by (i.) the use of sophisticated quadrature rules to deliver HOS accuracy; (ii.) the design of preconditioned iterative solvers with suitable acceleration \[24\]; and (iii) new strategies to avoid periodizing the Green function \[25, 26, 27, 28, 29, 30, 31, 32\]. As a result, these are an important alternative to volumetric approaches, but two properties render them non–competitive for the parameterized layered media problems we consider as compared with the methods we advocate here: (i.) For geometries specified by the real value $\varepsilon$ (the departure of the interface shapes from flat), an IE solver will return the scattering returns only for one value of $\varepsilon$. If this value is changed then the solver must be run again; (ii.) the dense, non–symmetric
positive definite systems of linear equations which must be inverted with each simulation.

As we have shown, see e.g. [33, 34, 35, 36], a “High–Order Perturbation of Surfaces” (HOPS) approach can convincingly address these concerns. These formulations maintain the useful properties of classical IE algorithms (e.g., surface formulation and exact enforcement of far–field conditions) while avoiding the flaws listed above: (i.) Since HOPS methods are built upon expansions in the perturbation parameter, \( \varepsilon \), once the Taylor coefficients are recovered, it is simply a matter of summing these (rather than beginning a new simulation) for any given choice of \( \varepsilon \) to recover the scattering quantities; (ii.) due to the perturbative nature of the scheme, at every Taylor order one need only invert a single, sparse operator corresponding to the order–zero (flat–interface) approximation of the problem.

Regardless of method used, the formulation of the governing equations strongly influences the performance of these approaches. With this in mind, following the guidance in [37, 38], we recently investigated the surface formulation of this problem in terms of Impedance–Impedance Operators (IIOs) [34, 39] which avoid the Dirichlet eigenvalues that plague the Dirichlet–Neumann Operators (DNOs) of more straightforward statements [40]. This non–overlapping Domain Decomposition Method (DDM) was first described for Laplace’s equation by Lions [41] and adapted to the Helmholtz problem by Després [42, 43, 37]. On interior layers these IIOs are unitary and they deliver a very well–conditioned algorithm. We utilize a formulation of the problem in terms of IIOs here.

Before leaving our discussion of numerical approaches, we mention the recent work of J. Lin [44] on IE methods for HMs. In this delicate and careful study, Lin describes a novel method for simulating the Green function associated to the relevant indefinite Helmholtz equation. This requires sophisticated grid refinement technology to resolve the boundary between regions of elliptic and hyperbolic behavior of the fundamental solution. We note that the approach outlined in this work does not require any such refinement, and we view it as an additional advantage of our HOPS algorithm.

The rest of the paper is organized as follows: In § 2 we state the governing equations for scattering of linear waves by a periodic layered medium with special discussions of the field equations in § 2.1, the interfacial boundary conditions in § 2.2, and transparent boundary conditions in § 2.3. We recall our DDM in § 3 and our HOPS scheme in § 4. Finally, we conclude with numerical results in § 5 featuring specific discussions of implementation in
§ 5.1, validation in § 5.2, and comparision with results in the literature in § 5.3.

2. Governing Equations

We begin with the constituitive relations between the electric displacement, \( \mathbf{D} \), the magnetic induction, \( \mathbf{B} \), the electric field, \( \mathbf{E} \), and the magnetic field, \( \mathbf{H} \),

\[
\mathbf{D} = \varepsilon_0 \varepsilon \mathbf{E}, \quad \mathbf{B} = \mu_0 \mu \mathbf{H},
\]

where \( \varepsilon_0 \) and \( \mu_0 \) are the permittivity and permeability of the vacuum, and \( \varepsilon \) and \( \mu \) are the relative permittivity and permeability tensors [45]. We focus upon non–magnetic materials so that \( \mu = \mathbb{I} \), and, after diagonalization, we have

\[
\varepsilon = \begin{pmatrix}
\varepsilon_x & 0 & 0 \\
0 & \varepsilon_y & 0 \\
0 & 0 & \varepsilon_z
\end{pmatrix}.
\]

Using these, the time–harmonic Maxwell equations (in the absence of currents and charges) become

\[
\begin{align*}
curl \mathbf{E} &= i\omega \mathbf{B} = i\omega \varepsilon_0 \varepsilon \mathbf{H}, \quad (1a) \\
curl \mathbf{H} &= -i\omega \mathbf{D} = -i\omega \varepsilon_0 \varepsilon \mathbf{E}, \quad (1b)
\end{align*}
\]

where time dependence of the form \( \exp(-i\omega t) \) has been factored out.

2.1. Field Equation

We now seek a solution to (1) in Transverse Magnetic (TM) polarization so that all quantities are \( y \)–invariant (the transverse direction) and the magnetic field has the form \( \mathbf{H} = (0, v(x, z), 0)^T \). To accomplish this we write (1) entirely in terms of \( \mathbf{H} \) and, in turn, \( v \). By solving (1b) for \( \mathbf{E} \) and inserting this into (1a) we find

\[
\begin{align*}
curl \left[-\frac{1}{i\omega \varepsilon_0 \varepsilon} \varepsilon^{-1} \begin{pmatrix}
\varepsilon_x & 0 & 0 \\
0 & \varepsilon_y & 0 \\
0 & 0 & \varepsilon_z
\end{pmatrix} \begin{pmatrix}
0 \\
v(x, z) \\
0
\end{pmatrix} \right] &= i\omega \varepsilon_0 \varepsilon \mathbf{H}.
\end{align*}
\]

Upon using the \( y \)–invariance of \( v \) we find that the \( y \)–component of (2) becomes

\[
\text{div} [A \nabla v] + k_0^2 v = 0,
\]
and

\[ A = \begin{pmatrix} (1/\epsilon_z) & 0 \\ 0 & (1/\epsilon_x) \end{pmatrix}, \]

which is not the inverse of \( \epsilon \).

**Remark 2.1.** We note that the same derivation could be conducted for Transverse Electric (TE) polarization resulting in the governing equation

\[ \text{div}[(1/\epsilon_y)\nabla v] + k_0^2 v = 0, \]

which, while interesting, is standard and can be treated with existing methods [46].

**Remark 2.2.** In the case of an isotropic material, \( \epsilon = \epsilon_r I \), we find the familiar Helmholtz equation

\[ \Delta v + \epsilon_r k_0^2 v = 0. \]

**Remark 2.3.** As we mentioned above, rather than model an HMM we chose to simulate a natural HM, namely hBN. For this we used the permittivity specified in [11]

\[ \epsilon_m = \epsilon_{\infty,m} \left( 1 + \frac{(\omega_{\text{LO},m})^2 - (\omega_{\text{TO},m})^2}{(\omega_{\text{TO},m})^2 - \omega^2 - i\omega \Gamma_m} \right), \quad m \in \{\|, \perp\}, \]

where

\[ \epsilon_{\infty,\perp} = 4.87, \quad \Gamma_{\perp} = 5 \text{ cm}^{-1}, \quad \omega_{\text{TO},\perp} = 1370 \text{ cm}^{-1}, \quad \omega_{\text{LO},\perp} = 1610 \text{ cm}^{-1}, \]

and

\[ \epsilon_{\infty,\|} = 2.95, \quad \Gamma_{\|} = 4 \text{ cm}^{-1}, \quad \omega_{\text{TO},\|} = 780 \text{ cm}^{-1}, \quad \omega_{\text{LO},\|} = 830 \text{ cm}^{-1}. \]

From these we form

\[ \epsilon^{hBN} = \begin{pmatrix} \epsilon_{\perp} & 0 & 0 \\ 0 & \epsilon_{\perp} & 0 \\ 0 & 0 & \epsilon_{\|} \end{pmatrix}. \]
2.2. Interfacial Boundary Conditions

At this point we fixate upon a ($y$–invariant) layered structure with $M$ interfaces located at

$$z = a^{(m)} + g^{(m)}(x), \quad 1 \leq m \leq M,$$

which are $d$–periodic,

$$g^{(m)}(x + d) = g^{(m)}(x), \quad 1 \leq m \leq M,$$

see Figure 1. These define the $(M + 1)$ domains

$$S^{(0)} = \{(x, z) \mid z > a^{(1)} + g^{(1)}(x)\},$$

$$S^{(m)} = \{(x, z) \mid a^{(m+1)} + g^{(m+1)}(x) < z < a^{(m)} + g^{(m)}(x)\}, \quad 1 \leq m \leq M - 1,$$

$$S^{(M)} = \{(x, z) \mid z < a^{(M)} + g^{(M)}(x)\},$$

with upward pointing normals

$$\mathbf{N}^{(m)} = \left( \begin{array}{c} -\partial_x g^{(m)} \\ 0 \\ 1 \end{array} \right).$$
These domains are filled with homogeneous non–magnetic materials with relative permittivity tensors $\varepsilon^{(m)}$, and the uppermost and lowermost layers are isotropic dielectrics so that for $m \in \{0, M\}$, $\varepsilon^{(m)} = \varepsilon^{(m)}_0$, $\varepsilon^{(m)}(m) \in \mathbb{R}^+$. Additionally, we consider the case where two-dimensional materials are present at the layer interfaces which we model with an interfacial current [47]. The structure is illuminated from above by radiation of frequency $\omega$ at angle $\theta$ that has the form

$$v^i = e^{i\alpha x - i\gamma_{(0)} z}, \quad \alpha = \sqrt{\varepsilon^{(0)} k_0 \sin(\theta)}, \quad \gamma_{(0)} = \sqrt{\varepsilon^{(0)} k_0 \cos(\theta)}.$$

The derivations in the previous section demonstrate that the transverse component of the magnetic field in layer $0 \leq m \leq M$, $\nu^{(m)}$, is governed by a Helmholtz equation of the form

$$\text{div} \left[ A^{(m)} \nabla \nu^{(m)} \right] + k_0^2 \nu^{(m)} = 0, \quad 0 \leq m \leq M, \quad (4)$$

where

$$A^{(m)} = \begin{pmatrix} \frac{1}{\varepsilon^{(m)}_z} & 0 \\ 0 & \frac{1}{\varepsilon^{(m)}_x} \end{pmatrix},$$

which must be supplemented with appropriate boundary conditions. First, each of the fields is quasiperiodic

$$\nu^{(m)}(x + d, z) = e^{i\alpha d} \nu^{(m)}(x, z), \quad 0 \leq m \leq M. \quad (5)$$

Next, at the interfaces $z = a^{(m)} + g^{(m)}(x)$, we know that, in the presence of interfacial currents, the tangential components of the electric and magnetic fields must satisfy [47]

$$\mathbf{N}^{(m)} \times \mathbf{E} = 0, \quad \mathbf{N}^{(m)} \times \mathbf{H} = |\mathbf{N}^{(m)}| \mathbf{j}_{s}^{(m)}, \quad 1 \leq m \leq M,$$

where $\mathbf{j}_{s}^{(m)}$ is the surface current at the $m$–th interface. Following [47], and inspired by Ohm’s Law, we model this with the relation

$$\mathbf{j}_{s}^{(m)} = \sigma^{(m)} \left( \frac{\mathbf{E}^{(m)} \cdot \mathbf{T}^{(m)}}{\mathbf{T}^{(m)} \cdot \mathbf{T}^{(m)}} \right) \mathbf{T}^{(m)}, \quad 1 \leq m \leq M,$$

where $\mathbf{T}^{(m)}$ is a tangent to the interface.

Using a straightforward generalization of [47], in TM polarization the tangential continuity of the electric field yields

$$-\mathbf{N}^e(m - 1)[\nu^{(m-1)}] - \mathbf{N}^u(m)[\nu^{(m)}] = \nu^{(m)}, \quad 1 \leq m \leq M. \quad (6)$$
\[ \nu^{(m)} = \begin{cases} \mathcal{N}_t(0)[\nu^i], & m = 1, \\ 0, & m > 1, \end{cases} \]

and the \( A^{(m)} \)-modified upper/lower exterior-pointing surface normal derivatives are defined by

\[ \mathcal{N}_u^{(m)}[\nu^{(m)}] := \mathbf{N}^{(m)} \cdot (A^{(m)} \nabla \nu^{(m)}), \quad z = a^{(m)} + g^{(m)}(x), \]
\[ \mathcal{N}_t^{(m)}[\nu^{(m)}] := -\mathbf{N}^{(m+1)} \cdot (A^{(m)} \nabla \nu^{(m)}), \quad z = a^{(m+1)} + g^{(m+1)}(x). \]

Continuing, the tangential boundary condition on the magnetic field gives

\[ \nu^{(m-1)} - \nu^{(m)} + \left| \mathbf{N}^{(m)} \right|^{-1} p^{(m)} \mathcal{N}_u^{(m)}[\nu^{(m)}] = \xi^{(m)}, \quad 1 \leq m \leq M, \tag{7} \]

where

\[ \xi^{(m)} = \begin{cases} -\nu^i, & m = 1, \\ 0, & m > 1. \end{cases} \]

**Remark 2.4.** Arguably the most influential two-dimensional material in the field of plasmonics is graphene [48, 49]. To give a flavor of the form which \( \sigma^{(m)} \) might take we note that, while the correct modeling of the electromagnetic properties of graphene is still open, one reasonable choice for the surface current is a Drude model [48, 49] of the form

\[ \hat{\sigma}_D = \frac{\sigma_D}{\epsilon_0 c_0}, \quad \sigma_D = \sigma_0 \left( \frac{4 E_F / \pi}{\Gamma - i \hbar \omega} \right), \quad \sigma_0 = \pi \epsilon_0 c_0 \alpha, \tag{8} \]

where \( \alpha \) is the fine structure constant, \( E_F > 0 \) is the (local) Fermi level position, and \( \Gamma := \hbar \gamma \), where \( \hbar \) is the reduced Planck’s constant and \( \gamma \) is the relaxation rate. In our simulations we used \( E_F = 0.45 \) eV and \( \Gamma = 2.6 \) meV.

### 2.3. Transparent Boundary Conditions and the Dispersion Relation

We require two more boundary conditions to specify a unique solution: The Upward and Downward Propagating Conditions (UPC/DPC). We derive the DPC and simply state the UPC, but for each we require artificial boundaries, \( \{ z = \overline{a} \} \) and \( \{ z = \underline{a} \} \), where

\[ \overline{a} > a^{(1)} + \left| g^{(1)} \right|_{L^\infty}, \quad \underline{a} < a^{(M)} - \left| g^{(M)} \right|_{L^\infty}. \]
For the DPC we seek plane–wave solutions of the form
\[ e^{i\alpha_p x - i\gamma_p^{(M)}(z-a)}, \quad \alpha_p = \alpha + \frac{2\pi p}{d}. \]
These are solutions of (4) in \( \{z < a\} \) if
\[ \frac{1}{\varepsilon_z^{(M)}}(i\alpha_p)^2 + \frac{1}{\varepsilon_x^{(M)}}(i\gamma_p^{(M)})^2 + k_0^2 = 0, \]
which can be simplified to the dispersion relation for uniaxial materials in TM polarization
\[ \frac{\alpha_p^2}{\varepsilon_z^{(M)}} + \frac{(\gamma_p^{(M)})^2}{\varepsilon_x^{(M)}} = k_0^2. \]
Notice that if the \( M \)-th layer is isotropic then \( \varepsilon_x^{(M)} = \varepsilon_z^{(M)} = \varepsilon^{(M)} \) and one redisCOVERS the classical dispersion relation,
\[ \alpha_p^2 + (\gamma_p^{(M)})^2 = \varepsilon^{(M)} k_0^2. \]
In order to specify the DPC we make the following choice for \( \gamma_p^{(M)} \),
\[ \gamma_p^{(M)} = \left( \varepsilon_x^{(M)} k_0^2 + \left( -\varepsilon_x^{(M)} \right) \left( \frac{-\varepsilon_x^{(M)}}{\varepsilon_z^{(M)}} \right) \alpha_p^2 \right)^{1/2}, \quad \text{Im} \left\{ \gamma_p^{(M)} \right\} \geq 0, \]
which guarantees that solutions are bounded as \( z \to -\infty \). Separation of variables gives
\[ v^{(M)}(x, z) = \sum_{p=-\infty}^{\infty} \hat{\mu}_p e^{i\alpha_p x - i\gamma_p^{(M)}(z-a)}, \]
and we observe that
\[ v^{(M)}(x, a) = \sum_{p=-\infty}^{\infty} \hat{\mu}_p e^{i\alpha_p x} = \mu(x), \quad \hat{\mu}_p = \frac{1}{d} \int_0^d \mu(x) e^{-i\alpha_p x} dx. \]
It is a simple matter to compute
\[ \partial_z v^{(M)}(x, a) = \sum_{p=-\infty}^{\infty} (-i\gamma_p^{(M)}) \hat{\mu}_p e^{i\alpha_p x} =: T^{(M)}[\mu], \]
which defines the order–one Fourier multiplier $T^{(M)}$. From these calculations it is clear that the DPC can be specified transparently at the artificial boundary with
\[
\partial_z v^{(M)} - T^{(M)}[v^{(M)}] = 0, \quad z = a. \tag{10}
\]
In a similar fashion [39], the UPC can be specified by
\[
\partial_z v^{(0)} + T^{(0)}[v^{(0)}] = 0, \quad z = \bar{a}, \tag{11}
\]
where
\[
T^{(0)}[\mu] := \sum_{p=-\infty}^{\infty} (-i\gamma^{(0)}_p) \hat{\mu}_p e^{i\alpha_p x}.
\]

Gathering all of our developments (Equations (4), (7), (6), (11), (10), and (5)) together we find the following set of governing equations
\begin{align*}
\text{div} \left[ A^{(m)} \nabla v^{(m)} \right] + k_0^2 v^{(m)} &= 0, \quad 0 \leq m \leq M, \tag{12a} \\
v^{(m-1)} - v^{(m)} + |N^{(m)}|^{-1} p^{(m)} N^u(m) [v^{(m)}] &= \xi^{(m)}, \quad 1 \leq m \leq M, \tag{12b} \\
-N^e(m-1)[v^{(m-1)}] - N^u(m)[v^{(m)}] &= v^{(m)}, \quad 1 \leq m \leq M, \tag{12c} \\
\partial_z v^{(0)} + T^{(0)}[v^{(0)}] &= 0, \quad z = \bar{a}, \tag{12d} \\
\partial_z v^{(M)} - T^{(M)}[v^{(M)}] &= 0, \quad z = a, \tag{12e} \\
v^{(m)}(x + d, z) &= e^{i\alpha_d} v^{(m)}(x, z). \tag{12f}
\end{align*}

3. A Non–Overlapping Domain Decomposition

Following our previous work [39], we restate (12) using a Non–Overlapping Domain Decomposition. For this we follow the lead of Després [42, 43] by using carefully chosen Impedance–Impedance Operators (IIOs) which are free of the artificial singularities which plague other surface operators such as Dirichlet–Neumann Operators (DNOs). To summarize these developments we begin by defining the order–$r$ Fourier multipliers
\begin{align*}
Y^{(m)}[\phi] := \sum_{p=-\infty}^{\infty} \hat{Y}^{(m)}_p \hat{\phi}_p e^{i\alpha_p x}, \quad Z^{(m)}[\phi] := \sum_{p=-\infty}^{\infty} \hat{Z}^{(m)}_p \hat{\phi}_p e^{i\alpha_p x}, \\
|\hat{Y}^{(m)}_p|, |\hat{Z}^{(m)}_p| \sim (1 + |p|^{r/2})^{r/2}, \quad r \in \{0, 1\}.
\end{align*}
and rearrange the boundary conditions, (12b) & (12c), by the operator

$$P^{(m)} = \begin{pmatrix} -Y^{(m)} & -I \\ Z^{(m)} & -I \end{pmatrix},$$

where \((Y^{(m)} + Z^{(m)})\) is chosen to be invertible so that this transformation itself can be inverted. We point out that Despré made the choice \(Y^{(m)} = Z^{(m)} = i\eta, \eta \in \mathbb{R}^+\) so that \(r = 0\) \([42, 43]\).

Defining the surface impedances

$$U^{(m), \ell}(x) := N^{\ell}(m)[v^{(m)}] - Y^{(m+1)}[v^{(m)}],$$
$$U^{(m), u}(x) := N^u(m)[v^{(m)}] - Z^{(m)}[v^{(m)}],$$
$$\tilde{U}^{(m), \ell}(x) := N^{\ell}(m)[v^{(m)}] + Z^{(m+1)}[v^{(m)}],$$
$$\tilde{U}^{(m), u}(x) := N^u(m)[v^{(m)}] + Y^{(m)}[v^{(m)}],$$

the boundary conditions (12b) & (12c) become

$$U^{(m-1), \ell} + \tilde{U}^{(m), u} + F^{(m)}U^{(m), u} + \tilde{F}^{(m)}\tilde{U}^{(m), u} = \zeta^{(m)},$$
$$\tilde{U}^{(m-1), \ell} + U^{(m), u} + G^{(m)}U^{(m), u} + \tilde{G}^{(m)}\tilde{U}^{(m), u} = \psi^{(m)},$$

where

$$\zeta^{(m)} = -v^{(m)} - Y^{(m)}[\zeta^{(m)}],$$
$$\psi^{(m)} = -v^{(m)} + Z^{(m)}[\zeta^{(m)}],$$
$$F^{(m)} = -Y^{(m)} \left[ p^{(m)} \left| N^{(m)} \right|^{-1} Y^{(m)} \right] \left( Y^{(m)} + Z^{(m)} \right)^{-1},$$
$$\tilde{F}^{(m)} = -Y^{(m)} \left[ p^{(m)} \left| N^{(m)} \right|^{-1} Z^{(m)} \right] \left( Y^{(m)} + Z^{(m)} \right)^{-1},$$
$$G^{(m)} = Z^{(m)} \left[ p^{(m)} \left| N^{(m)} \right|^{-1} Y^{(m)} \right] \left( Y^{(m)} + Z^{(m)} \right)^{-1},$$
$$\tilde{G}^{(m)} = Z^{(m)} \left[ p^{(m)} \left| N^{(m)} \right|^{-1} Z^{(m)} \right] \left( Y^{(m)} + Z^{(m)} \right)^{-1}.$$

We direct the interested reader to our previous work \([39]\) for full details.

To close (and simplify) this system of equations we introduce the following Impedance–Impedance Operators (IIOs).

**Definition 3.1.** Given an integer \(s \geq 0\) and any \(\delta > 0\), if \(g^{(1)} \in C^{s+3/2+\delta}\) then, for order-\(r \ (r \in \{0, 1\})\) Fourier multipliers \(\{Y^{(1)}, Z^{(1)}\}\), if a unique
quasiperiodic solution exists of

\[
\text{div} [A^{(0)} \nabla v^{(0)}] + k_0^2 v^{(0)} = 0, \quad a^{(1)} + g^{(1)}(x) < z < \pi, \quad (13a)
\]
\[
\partial_z v^{(0)} + T^{(0)}[v^{(0)}] = 0, \quad z = \pi, \quad (13b)
\]
\[
\mathcal{N}^\ell(0)[v^{(0)}] - Y^{(1)}[v^{(0)}] = U^{(0), \ell}, \quad z = a^{(1)} + g^{(1)}(x), \quad (13c)
\]

we define the upper IIO

\[
Q[U^{(0), \ell}] = Q(\bar{a}, a^{(1)}, g^{(1)})[U^{(0), \ell}] := \tilde{U}^{(0), \ell} = \mathcal{N}^\ell(0)[v^{(0)}] + Z^{(1)}[v^{(0)}]. \quad (13d)
\]

**Definition 3.2.** Given an integer \( s \geq 0 \) and any \( \delta > 0 \), if \( g^{(M)} \in C^{s+3/2+\delta} \) then, for order–r \(( r \in \{0, 1\} \) ) Fourier multipliers \( \{Y^{(M)}, Z^{(M)}\} \), if a unique quasiperiodic solution exists of

\[
\text{div} [A^{(M)} \nabla v^{(M)}] + k_0^2 v^{(M)} = 0, \quad a < z < a^{(M)} + g^{(M)}(x), \quad (14a)
\]
\[
\mathcal{N}^u(M)[v^{(M)}] - Z^{(M)}[v^{(M)}] = U^{(M), u}, \quad z = a^{(M)} + g^{(M)}(x), \quad (14b)
\]
\[
\partial_z v^{(M)} - T^{(M)}[v^{(M)}] = 0, \quad z = a, \quad (14c)
\]

we define the lower IIO

\[
S[U^{(M), u}] = S(a, a^{(M)}, g^{(M)})[U^{(M), u}] := \tilde{U}^{(M), u} = \mathcal{N}^u(M)[v^{(M)}] + Y^{(M)}[v^{(M)}]. \quad (14d)
\]

**Definition 3.3.** Given an integer \( s \geq 0 \) and any \( \delta > 0 \), if \( g^{(m)}, g^{(m+1)} \in C^{s+3/2+\delta} \) then, for order–r \(( r \in \{0, 1\} \) ) Fourier multipliers \( \{Y^{(m)}, Y^{(m+1)}, Z^{(m)}, Z^{(m+1)}\} \), if a unique quasiperiodic solution exists of

\[
\text{div} [A^{(m)} \nabla v^{(m)}] + k_0^2 v^{(m)} = 0, \quad a^{(m+1)} + g^{(m+1)}(x) < z < a^{(m)} + g^{(m)}(x), \quad (15a)
\]
\[
\mathcal{N}^u(m)[v^{(m)}] - Z^{(m)}[v^{(m)}] = U^{(m), u}, \quad z = a^{(m)} + g^{(m)}(x), \quad (15b)
\]
\[
\mathcal{N}^\ell(m)[v^{(m)}] - Y^{(m+1)}[v^{(m)}] = U^{(m), \ell}, \quad z = a^{(m+1)} + g^{(m+1)}(x), \quad (15c)
\]

we define an inner IIO

\[
R^{(m)} \begin{pmatrix} U^{(m), u} \\ U^{(m), \ell} \end{pmatrix} = R^{(m)}(a^{(m)}, g^{(m)}, a^{(m+1)}, g^{(m+1)}) \begin{pmatrix} U^{(m), u} \\ U^{(m), \ell} \end{pmatrix}
\]
\[
= \begin{pmatrix} R^{(m), uu} & R^{(m), u\ell} \\ R^{(m), \ell u} & R^{(m), \ell\ell} \end{pmatrix} \begin{pmatrix} U^{(m), u} \\ U^{(m), \ell} \end{pmatrix} := \begin{pmatrix} \tilde{U}^{(m), u} \\ \tilde{U}^{(m), \ell} \end{pmatrix} = \begin{pmatrix} \mathcal{N}^u(m)[v^{(m)}] + Y^{(m)}[v^{(m)}] \\ \mathcal{N}^\ell(m)[v^{(m)}] + Z^{(m+1)}[v^{(m)}] \end{pmatrix}. \quad (15d)
\]
Remark 3.4. As far as we are aware, the uniqueness of solutions to the problems (13), (14), and (15) is still an open question. However, it is known (see, e.g., [50]) that in the case of an isotropic material, $\epsilon_x^{(m)} = \epsilon_y^{(m)} = \epsilon_z^{(m)}$, these problems are well-posed provided that

$$\text{Im} \left\{ \int_0^d (Y^{(m)} \varphi) \bar{\varphi} \, dx \right\} > 0, \quad \text{Im} \left\{ \int_0^d (Z^{(m)} \varphi) \bar{\varphi} \, dx \right\} > 0.$$ 

Therefore, the choice of Desprès [42, 43], $Y^{(m)} = Z^{(m)} = i\eta$, $\eta > 0$, ensures well-defined IIOs.

Following [39] we can write this system of equations as

$$AV = R,$$  \hspace{1cm} (16)

where

$$V := \begin{pmatrix} U^{(0),\ell} \\ U^{(1),u} \\ U^{(1),\ell} \\ \vdots \\ U^{(M-1),u} \\ U^{(M-1),\ell} \\ U^{(M),u} \end{pmatrix}, \quad R := \begin{pmatrix} \zeta^{(1)} \\ \psi^{(1)} \\ \vdots \\ \zeta^{(M)} \\ \psi^{(M)} \end{pmatrix}.$$

Also

$$A := \begin{pmatrix} D^{(1)} & U^{(1)} & 0 & 0 & \cdots & 0 \\ L^{(2)} & D^{(2)} & U^{(2)} & 0 & \cdots & 0 \\ 0 & \ddots & \ddots & \ddots & \ddots & 0 \\ 0 & 0 & \ddots & \ddots & \ddots & 0 \\ 0 & \cdots & 0 & L^{(M-1)} & D^{(M-1)} & U^{(M-1)} \\ 0 & \cdots & 0 & 0 & L^{(M)} & D^{(M)} \end{pmatrix},$$

where

$$U^{(m)} = \begin{pmatrix} (I + \bar{F}^{(m)})R^{(m),u} \\ \bar{G}^{(m)}R^{(m),u} \end{pmatrix}, \quad 1 \leq m \leq M - 1,$$

and

$$L^{(m)} = \begin{pmatrix} 0 & 0 \\ 0 & R^{(m-1),u} \end{pmatrix}, \quad 2 \leq m \leq M,$$
and

\[
D^{(1)} = \left( I F^{(1)} + (I + \tilde{F}^{(1)}) R^{(1), uu} \right),
\]

\[
D^{(m)} = \left( I F^{(m)} + (I + \tilde{F}^{(m)}) R^{(m), uu} \right), \quad 2 \leq m \leq M - 1,
\]

\[
D^{(M)} = \left( I F^{(M)} + (I + \tilde{F}^{(M)}) S \right).
\]

4. A High–Order Perturbation of Surfaces Method

At this point we have several options for solving our governing equations, (16). We adopt a geometric perturbation approach based upon the assumption

\[
y^{(m)}(x) = \varepsilon f^{(m)}(x), \quad 1 \leq m \leq M,
\]

for \( \varepsilon \) sufficiently small and \( f^{(m)} \) sufficiently smooth (at least \( C^{s+3/2+\delta} \) for some \( \delta > 0 \)). In this case, the operator \( A = A(\varepsilon) \) and the right–hand–side \( R = R(\varepsilon) \) depend analytically upon \( \varepsilon \) so that

\[
A(\varepsilon) = \sum_{n=0}^{\infty} A_n \varepsilon^n, \quad R(\varepsilon) = \sum_{n=0}^{\infty} R_n \varepsilon^n. \tag{17}
\]

With this it can be shown that the solution \( V(\varepsilon) \) depends analytically upon \( \varepsilon \), so that

\[
V(\varepsilon) = \sum_{n=0}^{\infty} V_n \varepsilon^n, \tag{18}
\]

where, upon insertion of these forms into (16), we find at order \( O(\varepsilon^n) \),

\[
A_0 V_n = R_n - \sum_{\ell=0}^{n-1} A_{n-\ell} V_{\ell},
\]

or

\[
V_n = A_0^{-1} \left[ R_n - \sum_{\ell=0}^{n-1} A_{n-\ell} V_{\ell} \right]. \tag{19}
\]

We refer the interested reader to [39] and the references therein for a more formal justification of these developments, in particular, the demonstration
that the relevant IIOs, \( \{Q, R^{(m)}, S\} \), depend analytically upon the perturbation parameter \( \varepsilon \) which justifies the expansion of the terms \( \{A, R\} \) in convergent power series. We further mention that the paper [39] provides a possible path to establishing that, under certain hypotheses, unique solutions of (16) exist.

**Remark 4.1.** We anticipate that the smallness assumption on the perturbation variable, \( \varepsilon \), can be dropped provided that it is real and that there is no topological obstruction (e.g., intersecting layer interfaces). The papers [51, 52] provide one possible approach to establishing such a result.

5. Numerical Results

We now present the results of numerical experiments based upon the formulation of grating structures featuring hyperbolic materials stated above. We begin with a brief validation by the Method of Manufactured Solutions and follow up with simulations of structures appearing in the engineering literature.

5.1. Implementation

To simulate layered media problems featuring hyperbolic materials we utilize (16), the surface formulation of the governing equations in terms of IIOs which are functions of the interface height/slope \( \varepsilon \),

\[
A(\varepsilon)V(\varepsilon) = R(\varepsilon).
\]

As in [39], we seek a solution of the form (18) which is truncated after a finite number of orders, \( N \geq 0 \),

\[
V(\varepsilon) \approx V^N(\varepsilon) := \sum_{n=0}^{N} V_n \varepsilon^n. \tag{20}
\]

To find the \( V_n \) we must solve (19) for \( 0 \leq n \leq N \) which, in turn, requires the application of the operators \( A_n \) and the formation of the functions \( R_n \) which come from the series expansions of \( A \) and \( R \), respectively. For this we must be able to evaluate the operators \( \{F_n^{(m)}, F_n^{(m)}, G_n^{(m)}, \tilde{G}_n^{(m)}\} \) and the IIOs \( \{Q_n, R_n^{(m)}, S_n\} \). For the former, all of the details are provided in the papers [34, 39], while for the latter, the method of Transformed Field Expansions (TFE) [53, 51, 46] was used to simulate the IIOs. Again, all of the relevant
details are specified in [34, 39]. To summarize, we used a spectral Fourier–Chebyshev approach [12, 54, 14] where

$$V_n(x, z) \approx V_{N_x, N_z}(x, z) := \sum_{p=-N_x/2}^{N_x} \sum_{q=0}^{N_z} \hat{V}_{n,p,q} T_q(z/h)e^{i\alpha_p x},$$

and $T_q$ is the $q$–th Chebyshev polynomial. To find the Fourier–Chebyshev coefficients, $\{\hat{V}_{n,p,q}\}$, we used the collocation method by demanding that the governing equations be true at the gridpoints, e.g. on a layer $\{(0, d] \times [-h, h]\}$,

$$\{x_j = j(d/N_x) | 0 \leq j \leq N_x - 1\}, \quad \{z_r = h \cos(\pi r/N_z) | 0 \leq r \leq N_z\}.$$  

With fast Fourier and Chebyshev transforms [12, 54, 14] the resulting equations were solved efficiently and stably.

**Remark 5.1.** We point out that these developments eventually lead to the simulation of two–point boundary value problems for the quantities $\hat{V}_{n,p}(z)$ on $\{-h < z < h\}$ which we successfully addressed with our Chebyshev collocation method. In contrast to the approach of Lin [44] this did not require sophisticated grid refinement strategies despite the indefinite character of the boundary value problem to be solved.

A final, important, question is how the Taylor series, (20), in $\varepsilon$ is summed, e.g., the approximation of $\hat{V}_{p,q}(\varepsilon)$ by

$$\hat{V}_{p,q}^N(\varepsilon) := \sum_{n=0}^{N} \hat{V}_{n,p,q} \varepsilon^n.$$

For this, Padé approximation [55] has been used in conjunction with HOPS methods to great effect [56, 51] and we recommend its use here. Padé approximation seeks to estimate the truncated Taylor series $\hat{V}_{p,q}^N(\varepsilon)$ by the rational function

$$[L/M](\varepsilon) := \frac{a_L(\varepsilon)}{b^M(\varepsilon)} = \frac{\sum_{\ell=0}^{L} a_{\ell} \varepsilon^\ell}{1 + \sum_{m=1}^{M} b_m \varepsilon^m}, \quad L + M = N,$$

and

$$[L/M](\varepsilon) = \hat{V}_{p,q}^N(\varepsilon) + O(\varepsilon^{L+M+1});$$

well–known formulas for the coefficients $\{a_{\ell}, b_m\}$ can be found in [55]. This technique has remarkable properties of enhanced convergence, and we refer the interested reader to § 2.2 of Baker & Graves–Morris [55] and the insightful calculations of § 8.3 of Bender & Orszag [57] for a thorough discussion of the capabilities and limitations of Padé approximants.
5.2. Validation

To validate our scheme, we utilized the Method of Manufactured Solutions [58, 59, 60]. To summarize, consider the general system of partial differential equations subject to generic boundary conditions

\[ \mathcal{P}v = 0, \quad \text{in } \Omega, \]
\[ \mathcal{B}v = 0, \quad \text{at } \partial \Omega. \]

It is typically easy to implement a numerical algorithm to solve the nonhomogeneous version of this set of equations

\[ \mathcal{P}v = \mathcal{F}, \quad \text{in } \Omega, \]
\[ \mathcal{B}v = \mathcal{J}, \quad \text{at } \partial \Omega. \]

To test an implementation we began with the “manufactured solution,” \( \tilde{v} \), and set

\[ \mathcal{F}_v := \mathcal{P}\tilde{v}, \quad \mathcal{J}_v := \mathcal{J}\tilde{v}. \]

Thus, given the pair \( \{\mathcal{F}_v, \mathcal{J}_v\} \) we had an exact solution of the nonhomogeneous problem, namely \( \tilde{v} \). While this does not prove an implementation to be correct, if the function \( \tilde{v} \) is chosen to imitate the behavior of anticipated solutions (e.g., satisfying the boundary conditions exactly) then this gives us confidence in our algorithm.

For the current implementation we focused upon the three–layer problem \( (M = 2) \) and considered the quasiperiodic, outgoing solutions of the Helmholtz equation (13a)

\[ \begin{aligned}
    v_r^{(0)}(x, z) &:= A_r^{(0)} e^{i\alpha_r x + i\gamma^{(0)}_r z}, & r &\in \mathbb{Z}, & A_r^{(0)} &\in \mathbb{C}, \\
    v_r^{(2)}(x, z) &:= B_r^{(2)} e^{i\alpha_r x - i\gamma^{(2)}_r z}, & r &\in \mathbb{Z}, & B_r^{(2)} &\in \mathbb{C}.
\end{aligned} \]

and their counterparts for (14a)

\[ \begin{aligned}
    v_r^{(1)}(x, z) &:= A_r^{(1)} e^{i\alpha_r x + i\gamma^{(1)}_r z} + B_r^{(1)} e^{i\alpha_r x - i\gamma^{(1)}_r z}, & r &\in \mathbb{Z}, & A_r^{(1)}, B_r^{(1)} &\in \mathbb{C}.
\end{aligned} \]

Further, we considered the quasiperiodic solutions of the Helmholtz equation (15a)

\[ \begin{aligned}
    v_r^{(1)}(x, z) &:= A_r^{(1)} e^{i\alpha_r x + i\gamma^{(1)}_r z} + B_r^{(1)} e^{i\alpha_r x - i\gamma^{(1)}_r z}, & r &\in \mathbb{Z}, & A_r^{(1)}, B_r^{(1)} &\in \mathbb{C}.
\end{aligned} \]

We selected two simple sinusoidal profiles

\[ \begin{aligned}
    g^{(1)}(x) = \varepsilon f^{(1)}(x) &= \varepsilon \cos(2x), & g^{(2)}(x) = \varepsilon f^{(2)}(x) &= \varepsilon \sin(2x), \quad (21)
\end{aligned} \]
and defined, for any choice of the layer half–thickness $\bar{h}$, the Dirichlet and Neumann traces

\begin{align*}
\xi_r^{(0)}(x) &:= v_r^{(0)}(x, \bar{h} + g^{(1)}(x)), & \nu_r^{(0)}(x) &:= \mathcal{N}^{e}(0)[v_r^{(0)}(x, \bar{h} + g^{(1)}(x))], \\
\xi_r^{(1),h}(x) &:= v_r^{(1)}(x, \bar{h} + g^{(1)}(x)), & \nu_r^{(1),h}(x) &:= \mathcal{N}^{u}(1)[v_r^{(1)}(x, \bar{h} + g^{(1)}(x))], \\
\xi_r^{(1),-h}(x) &:= v_r^{(1)}(x, -\bar{h} + g^{(2)}(x)), & \nu_r^{(1),-h}(x) &:= \mathcal{N}^{e}(1)[v_r^{(1)}(x, -\bar{h} + g^{(2)}(x))], \\
\xi_r^{(2)}(x) &:= v_r^{(2)}(x, -\bar{h} + g^{(2)}(x)), & \nu_r^{(2)}(x) &:= \mathcal{N}^{u}(2)[v_r^{(2)}(x, -\bar{h} + g^{(2)}(x))].
\end{align*}

From these we defined, for any choices of the operators \{$Y^{(1)}, Z^{(1)}, Y^{(2)}, Z^{(2)}$\}, the impedances

\begin{align*}
V_r^{(0),\ell} &:= \nu^{(0)} - Y^{(1)}[\xi^{(0)}], & \tilde{V}_r^{(0),\ell} &:= \nu^{(0)} + Z^{(1)}[\xi^{(0)}], \quad (22a) \\
V_r^{(1),u} &:= \nu^{(1),h} - Z^{(1)}[\xi^{(1),h}], & \tilde{V}_r^{(1),u} &:= \nu^{(1),h} + Y^{(1)}[\xi^{(1),h}], \quad (22b) \\
V_r^{(1),\ell} &:= \nu^{(1),-h} - Y^{(2)}[\xi^{(1),-h}], & \tilde{V}_r^{(1),\ell} &:= \nu^{(1),-h} + Z^{(2)}[\xi^{(1),-h}], \quad (22c) \\
V_r^{(2),u} &:= \nu^{(2)} - Z^{(2)}[\xi^{(2)}], & \tilde{V}_r^{(2),u} &:= \nu^{(2)} + Y^{(2)}[\xi^{(2)}]. \quad (22d)
\end{align*}

We chose the following physical parameters

\begin{align*}
d = 2\pi, \quad \alpha = 0.1, \quad \hat{\varepsilon}^{(0)} = \hat{\varepsilon}^{(2)} &= \hat{I}, \quad \hat{\varepsilon}^{(1)} = \begin{pmatrix} e + 1.1i & 0 & 0 \\ 0 & e + 1.1i & 0 \\ 0 & 0 & -2.3 + 1.1i \end{pmatrix}, \\
\hat{\sigma}^{(1)} &= 0.2, \quad \hat{\sigma}^{(2)} = 0.45, \\
A_r^{(0)} &= -3 \delta_{r,2}, \quad B_r^{(2)} = 4 \delta_{r,2}, \quad A_r^{(1)} = -\varepsilon \delta_{r,2}, \quad B_r^{(1)} = \pi \delta_{r,2}, \quad (23)
\end{align*}

(\text{where} \delta_{r,s} \text{\ is the Kronecker delta\ in TM polarization, and the numerical parameters})

\begin{align*}
N_x &= 64, \quad N_y = 24, \quad N = 10, \quad a = 1/5, \quad b = 1/5. \quad (24)
\end{align*}

To illuminate the behavior of our scheme we made the Després [42, 43, 37] choice of operators

\begin{align*}
Y^{(1)} = Z^{(1)} = Y^{(2)} = Z^{(2)} = i\eta, \quad \eta = k_0, \quad (25)
\end{align*}

and studied four choices

\begin{align*}
\varepsilon &= 0.005, 0.01, 0.05, 0.1,
\end{align*}

20
in (21). For this we supplied the “exact” input data, \( \{ V_r^{(0)}, V_r^{(1),u}, V_r^{(1),\ell}, V_r^{(2),u} \} \), from (22) to our HOPS algorithm to simulate solutions of the IIO formulation of the three–layer scattering problem. We compared the output of this, \( \{ \tilde{V}_r^{(0),\ell}, \tilde{V}_r^{(1),u}, \tilde{V}_r^{(1),\ell}, \tilde{V}_r^{(2),u} \} \), with the “exact” output, \( \{ V_r^{(0),\ell}, V_r^{(1),u}, V_r^{(1),\ell}, V_r^{(2),u} \} \), by computing the relative error

\[
\text{Error}_{\text{rel}} := \left| \frac{\tilde{V}_r^{(0),\ell} - \tilde{V}_r^{(0),\ell,\text{approx}}}{L_\infty} \right| / \left| \tilde{V}_r^{(0),\ell} \right|_{L_\infty}.
\]

We note that the choice to measure the defect in the upper–layer quantity, \( \tilde{V}_r^{(0),\ell} \), was arbitrary, and measuring the mismatch in any of the other output quantities produced similar results.

To evaluate our implementation we selected the IIOs specified by (25), and we report our results in Figures 2 and 3. More specifically, Figure 2 displays both the rapid and stable decay of the relative error as \( N \) is increased, and how this rate of decay improves as \( \varepsilon \) is decreased. Figure 3 shows both how the error shrinks as \( \varepsilon \) becomes smaller, and that this rate is enhanced as \( N \) is increased.

\begin{figure}[h]
\centering
\includegraphics[width=0.5\textwidth]{figure2.png}
\caption{Plot of relative error with six choices of \( N = 0, 2, 4, 6, 8, 10 \) and four choices of \( \varepsilon = 0.005, 0.01, 0.05, 0.1 \) for IIO choice (25) with Taylor summation. Physical parameters were (23) and numerical discretization was (24).}
\end{figure}

5.3. Comparison with Published Results

Having verified the accuracy and reliability of our implementation we felt justified in simulating results which appear in the engineering literature, in particular the computations published by Kumar et al [11]. In this work
the authors investigated the dispersion relation of hybrid plasmon–phonon polaritons excited in a configuration consisting of graphene–hBN heterostructures. In this study the tunable graphene surface plasmons which are generated in the mid–infrared to terahertz regime were coupled to the hBN phonon polaritons which also exist in this regime.

Kumar et al studied the linear dispersion relation for a thin (50 nm thick) layer of hBN in air, and then recomputed this with a monolayer sheet of graphene attached to the hBN. In short, they computed the singularities of $A_0$, see (17), as the spatial wavenumber $q = 2\pi/d$ and illumination frequency $\omega = 2\pi/\lambda$ were varied. We have reproduced these results in the regimes of Type I hyperbolicity ($760 \text{ cm}^{-1} < \omega < 860 \text{ cm}^{-1}$) without graphene (Figure 4) and with graphene affixed above and below the hBN layer (Figure 5). In addition, we have computed in the Type II hyperbolicity range ($1000 \text{ cm}^{-1} < \omega < 1700 \text{ cm}^{-1}$) without graphene (Figure 6) and with graphene above and below the hBN layer (Figure 7).

In these plots we see the characteristic appearance of multiple slab polariton modes in the regions of hBN hyperbolicity, $\text{Re} \{\epsilon_x\} \text{Re} \{\epsilon_z\} < 0$, indicated by the yellow regions where

$$\log (\text{Re} \{\Delta\}) = \log (\text{Re} \{\text{cond}A_0\}),$$  \hspace{1cm} (26)

c.f. (17), becomes large, hinting at small values of the dispersion relation. For instance, in Figure 4 we find a range of frequencies between 780 and
830 cm\(^{-1}\) which feature *multiple* ranges of large \(\Delta\) indicating that several modes propagate in the hBN for these frequencies. In addition, we see that the number of such modes increases with increasing \(\omega\) in Figure 4 (Type I hyperbolicity) and with decreasing \(\omega\) in Figure 6 (Type II hyperbolicity). Additionally, these figures are *significantly* modified with the introduction of graphene. In both configurations an additional mode, of quite strong magnitude, is introduced at lower frequency than the hypebolic regions, which merges rather smoothly to this range as \(q\) increases, as noted in [11].

Beyond this we can use our solver for (16) to investigate whether one can realize these properties in an actual device. For this we introduce corrugations to the upper air/hBN and lower hBN/air interfaces shaped by

\[
f^{(1)}(x) = f^{(2)}(x) = \cos(2\pi x/d),
\]

which generate the necessary momentum to realize surface plasmon waves [49]. (We note that, by contrast, Kumar *et al* generate this momentum with periodically spaced *ribbons* of graphene.) We chose the following physical parameters

\[
d = 2\pi/q, \quad \theta = 0, \quad \epsilon^{(0)} = \epsilon^{(2)} = I, \quad \epsilon^{(1)} = \epsilon^{\text{hBN}}, \quad \hat{\sigma}^{(1)} = \hat{\sigma}^{(2)} = \begin{cases} 
0, \quad \hat{\sigma}_D,
\end{cases}
\]

(see (3) and (8)) in TM polarization, and the numerical parameters

\[
N_q = 201, \quad N_\omega = N_q + 1, \quad N_\chi = 16, \quad N_z = 16, \quad N = 4, \quad a = b = 1/2.
\]
Again, we made the Després choice of operators (25) and considered the value \( \varepsilon = 0.01 \) which is sufficiently large to generate a plasmonic response [61].

To study the response of these configurations under plane–wave illumination we computed the absorbance (the total energy minus the reflected and transmitted energies) which characterizes the energy propagating inside the hBN layer. Here we see in this nonlinear dispersion relation the strong resemblance between our device simulations and the predictions of the linear dispersion relation. More specifically we note the similarities between Figures 4 and 8 in the Type I hyperbolic regime without graphene, Figures 5 and 9 in the Type I hyperbolic regime with graphene, Figures 6 and 10 in the Type II hyperbolic regime without graphene, and Figures 7 and 11 in the Type II hyperbolic regime with graphene. Such results indicate that, in fact, such devices can be built and a construction strategy based upon periodically corrugated diffraction gratings is one realistic possibility [62].

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References

Figure 6: Linear dispersion relation for a layered air/hBN/air structure in the frequency range of Type II hyperbolicity of hBN.


Figure 7: Linear dispersion relation for a layered air/graphene/hBN/graphene/air structure in the frequency range of Type II hyperbolicity of hBN.


Figure 8: Nonlinear dispersion relation, (26), for a layered air/hBN/air structure in the frequency range of Type I hyperbolicity of hBN.


Figure 9: Nonlinear dispersion relation, (26), for a layered air/graphene/hBN/graphene/air structure in the frequency range of Type I hyperbolicity of hBN.


Figure 10: Nonlinear dispersion relation, (26), for a layered air/hBN/air structure in the frequency range of Type II hyperbolicity of hBN.


Figure 11: Nonlinear dispersion relation, (26), for a layered air/graphene/hBN/graphene/air structure in the frequency range of Type II hyperbolicity of hBN.


